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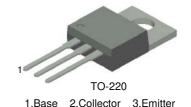
# FJP1943 PNP Epitaxial Silicon Transistor

## **Applications**

- · High-Fidelity Audio Output Amplifier
- · General Purpose Power Amplifier

## **Features**

- High Current Capability: I<sub>C</sub> = -17A.
- High Power Dissipation : 80watts.
- · High Frequency: 30MHz.
- High Voltage : V<sub>CEO</sub>= -250V
- · Wide S.O.A for reliable operation.
- · Excellent Gain Linearity for low THD.
- Complement to FJP5200
- Full thermal and electrical Spice models are available.
- · Same transistor is also available in:
  - -- TO264 package, 2SA1943/FJL4215: 150 watts
  - -- TO3P package, 2SA1962/FJA4213: 130 watts
  - -- TO220F package, FJPF1943: 50 watts



# Absolute Maximum Ratings\* $T_a = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Ratings	Units
BV <sub>CBO</sub>	Collector-Base Voltage	-250	V
BV <sub>CEO</sub>	Collector-Emitter Voltage	-250	V
BV <sub>EBO</sub>	Emitter-Base Voltage	-5	V
I <sub>C</sub>	Collector Current	-17	Α
I <sub>B</sub>	Base Current		А
P <sub>D</sub> Total Device Dissipation(T <sub>C</sub> =25°C) Derate above 25°C		80 0.64	W W/°C
T <sub>J</sub> , T <sub>STG</sub>	T <sub>STG</sub> Junction and Storage Temperature		°C

<sup>\*</sup> These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

## Thermal Characteristics\* T<sub>a</sub>=25°C unless otherwise noted

Symbol	Parameter	Ratings	Units	
$R_{ heta JC}$	Thermal Resistance, Junction to Case	1.25	°C/W	

<sup>\*</sup> Device mounted on minimum pad size

## h<sub>FE</sub> Classification

Classification	R	0
h <sub>FE1</sub>	55 ~ 110	80 ~ 160

# **Electrical Characteristics\*** $T_a$ =25°C unless otherwise noted

Symbol	Parameter Test Condition		Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	$I_C=-5mA$ , $I_E=0$	-250			٧
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> =-10mA, R <sub>BE</sub> =∞	-250			<b>V</b>
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	$I_E$ =-5mA, $I_C$ =0	-5			٧
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> =-230V, I <sub>E</sub> =0			-5.0	μА
I <sub>EBO</sub>	Emitter Cut-off Current	V <sub>EB</sub> =-5V, I <sub>C</sub> =0			-5.0	μА
h <sub>FE1</sub>	DC Current Gain	V <sub>CE</sub> =-5V, I <sub>C</sub> =-1A	55		160	
h <sub>FE2</sub>	DC Current Gain	V <sub>CE</sub> =-5V, I <sub>C</sub> =-7A	35	60		
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> =-8A, I <sub>B</sub> =-0.8A		-0.4	-3.0	V
V <sub>BE</sub> (on)	Base-Emitter On Voltage	V <sub>CE</sub> =-5V, I <sub>C</sub> =-7A		-1.0	-1.5	V
f <sub>T</sub>	Current Gain Bandwidth Product	V <sub>CE</sub> =-5V, I <sub>C</sub> =-1A		30		MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> =-10V, f=1MHz		360		pF

<sup>\*</sup> Pulse Test: Pulse Widt=20μs, Duty Cycle≤2%

# **Ordering Information**

Part Number	Marking	Package	Packing Method	Remarks
FJP1943RTU	J1943R	TO-220	TUBE	hFE1 R grade
FJP1943OTU	J1943O	TO-220	TUBE	hFE1 O grade

# **Typical Characteristics**

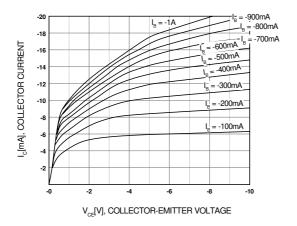


Figure 1. Static Characteristic

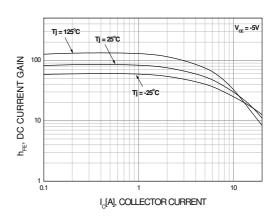


Figure 2. DC current Gain ( R Grade )

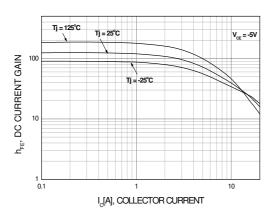


Figure 3. DC current Gain (O Grade)

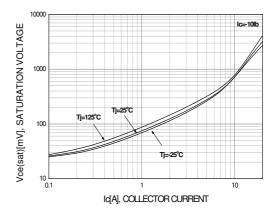


Figure 4. Collector-Emitter Saturation Voltage

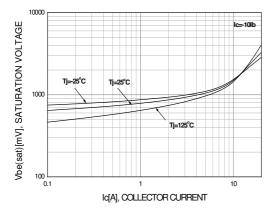


Figure 5. Base-Emitter Saturation Voltage

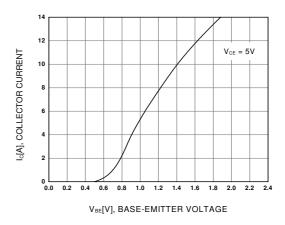


Figure 6. Base-Emitter On Voltage

# **Typical Characteristics**

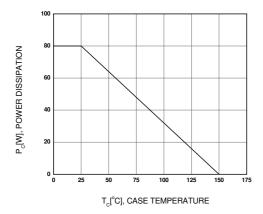


Figure 7. Power Derating

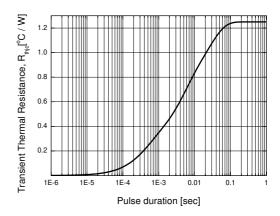
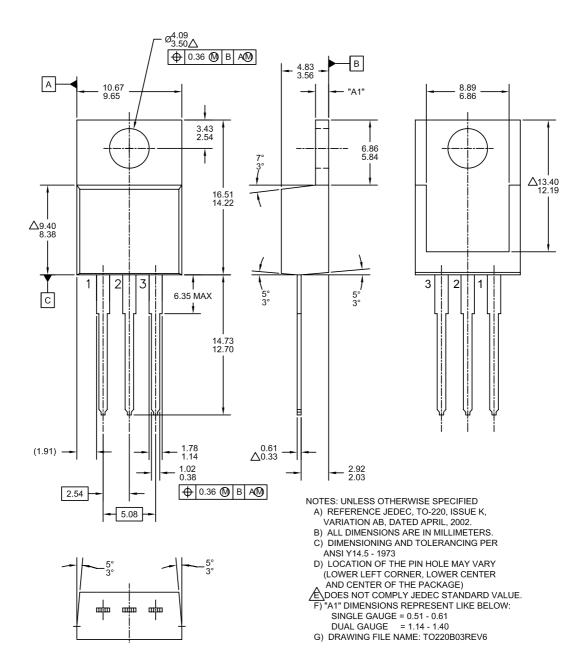


Figure 8. Thermal Resistance

## **Mechanical Dimensions**

# TO220







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